

N-Channel Logic Level Enhancement Mode Power MOSFET

MTB04N03Q8

BVDSS	30V
ID	25A
RDSON@VGS=10V, ID=18A	3.5mΩ (typ)
RDSON@VGS=4.5V, ID=12A	4.8mΩ (typ)

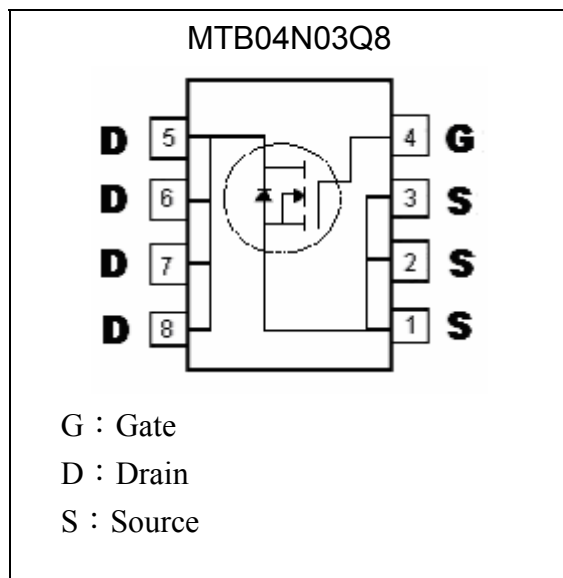
Description

The MTB04N03Q8 is a N-channel enhancement-mode MOSFET, providing the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost effectiveness. The SOP-8 package is universally preferred for all commercial-industrial surface mount applications and suited for low voltage applications such as DC/DC converters.

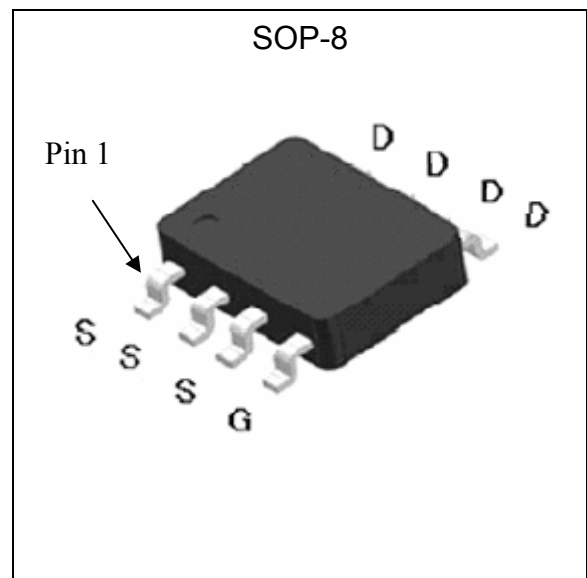
Features

- Single Drive Requirement
- Low On-resistance
- Fast Switching Characteristic
- Dynamic dv/dt rating
- Repetitive Avalanche Rated
- Pb-free lead plating package

Symbol



Outline



**Absolute Maximum Ratings** (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current @ T _C =25°C	I _D	25	A
Continuous Drain Current @ T _C =100°C		16	
Pulsed Drain Current	I _{DM}	100 *1	
Avalanche Current	I _{AS}	20	
Avalanche Energy @ L=0.1mH, I _D =20A, V _{DD} =15V	E _{AS}	40	mJ
Repetitive Avalanche Energy @ L=0.05mH	E _{AR}	0.3 *2	
Total Power Dissipation	P _D	T _A =25°C 2.5	W
		T _A =100°C 1	
Operating Junction and Storage Temperature Range	T _j , T _{stg}	-55~+150	°C

Thermal Data

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-case, max	R _{th,j-c}	25	°C/W
Thermal Resistance, Junction-to-ambient, max	R _{th,j-a}	50 *3	°C/W

- Note : 1. Pulse width limited by maximum junction temperature
2. Duty cycle ≤ 1%
3. Surface mounted on 1 in² copper pad of FR-4 board, 125°C/W when mounted on minimum copper pad

Characteristics (T_C=25°C, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV _{DSS}	30	-	-	V	V _{GS} =0, I _D =250μA
V _{GS(th)}	1.0	1.6	2.5	V	V _{DS} = V _{GS} , I _D =250μA
G _{FS} *1	-	32	-	S	V _{DS} = 5V, I _D =18A
I _{GSS}	-	-	±100	nA	V _{GS} =±20
I _{DSS}	-	-	1	μA	V _{DS} = 30V, V _{GS} = 0
	-	-	25		V _{DS} = 30V, V _{GS} = 0, T _j =125°C
R _{DS(ON)} *1	-	3.5	4	mΩ	V _{GS} = 10V, I _D =18A
	-	4.8	6	mΩ	V _{GS} = 4.5V, I _D =12A
Dynamic					
C _{iss}	-	4200	-	pF	V _{GS} =0V, V _{DS} =15V, f=1MHz
C _{oss}	-	405	-		
C _{rss}	-	400	-		

**Characteristics (T_c=25°C, unless otherwise specified)**

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Q _g (V _{GS} =10V) *1, 2	-	50	-	nC	V _{DS} =15V, V _{GS} =10V, I _D =18A
Q _g (V _{GS} =4.5V) *1, 2	-	30	-		
Q _{gs} *1, 2	-	8	-		
Q _{gd} *1, 2	-	17	-		
t _{d(ON)} *1, 2	-	18	-	ns	V _{DS} =15V, I _D =1A, V _{GS} =10V, R _{GS} =2.7Ω
t _r *1, 2	-	11	-		
t _{d(OFF)} *1, 2	-	65	-		
t _f *1, 2	-	15	-		
R _g	-	1.6	-	Ω	V _{GS} =15mV, V _{DS} =0V, f=1MHz
Source-Drain Diode					
I _S *1	-	-	10	A	
I _{SM} *3	-	-	40		
V _{SD} *1	-	-	1.2	V	I _F =I _S , V _{GS} =0V
t _{rr}	-	35	-	ns	I _F =I _S , dI _F /dt=100A/μs
Q _{rr}	-	14	-	nC	

Note : *1.Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

*2.Independent of operating temperature

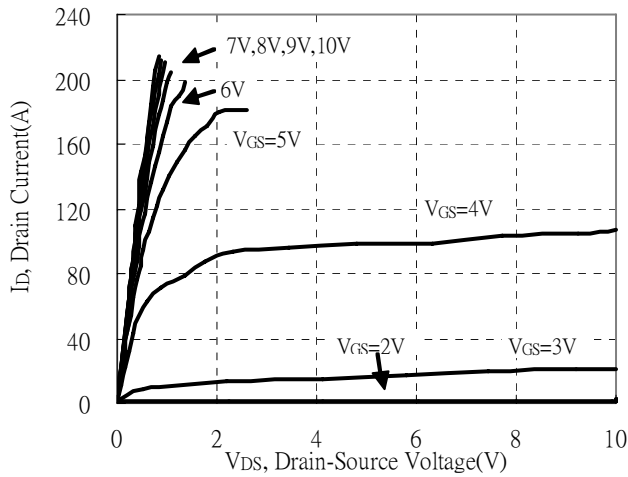
*3.Pulse width limited by maximum junction temperature.

Ordering Information

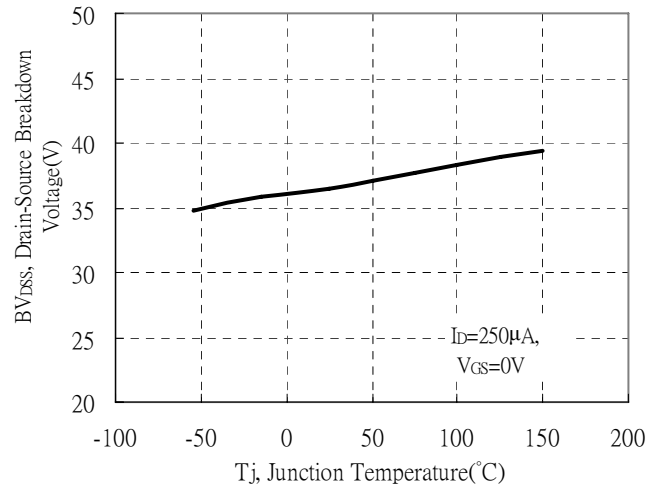
Device	Package	Shipping	Marking
MTB04N03Q8	SOP-8 (Pb-free lead plating package)	2500 pcs / Tape & Reel	B04N03

Typical Characteristics

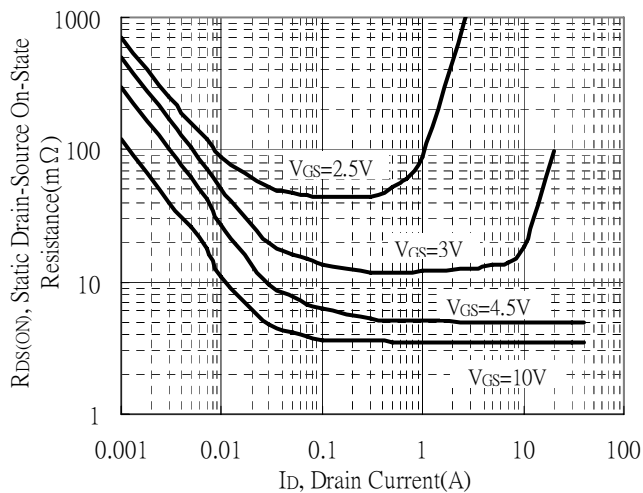
Typical Output Characteristics



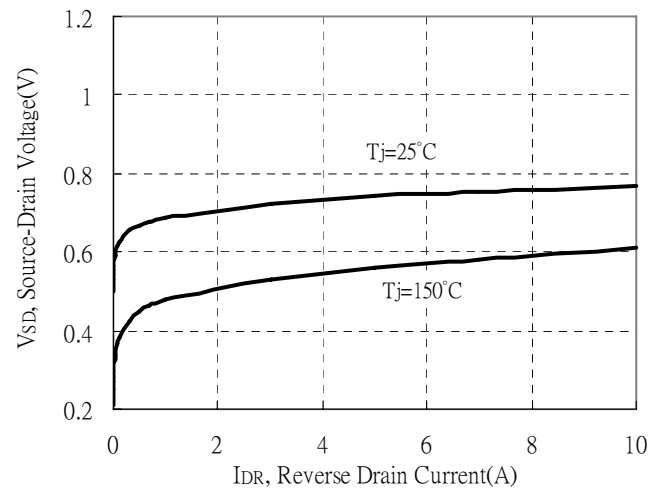
Breakdown Voltage vs Ambient Temperature



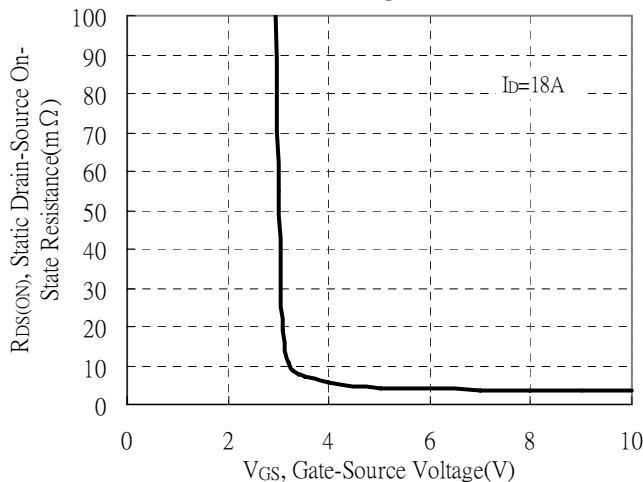
Static Drain-Source On-State resistance vs Drain Current



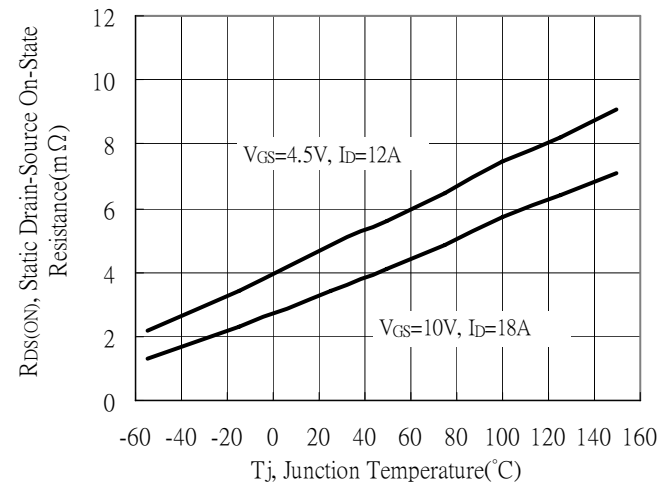
Reverse Drain Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

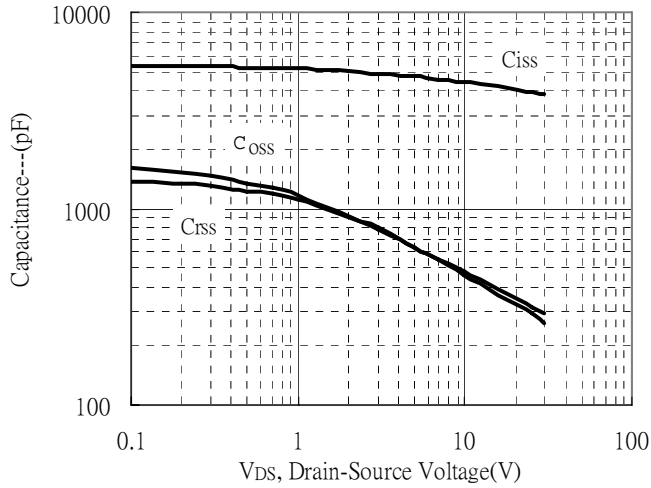


Drain-Source On-State Resistance vs Junction Temperature

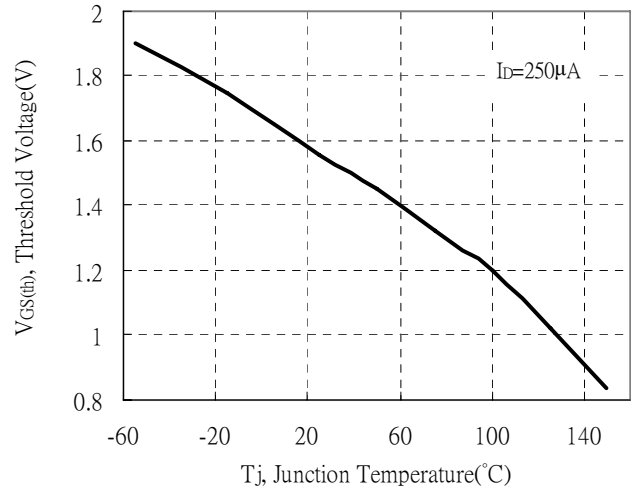


Typical Characteristics(Cont.)

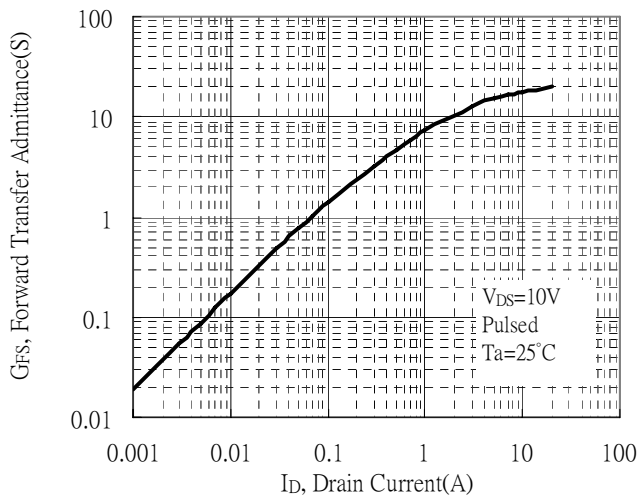
Capacitance vs Drain-to-Source Voltage



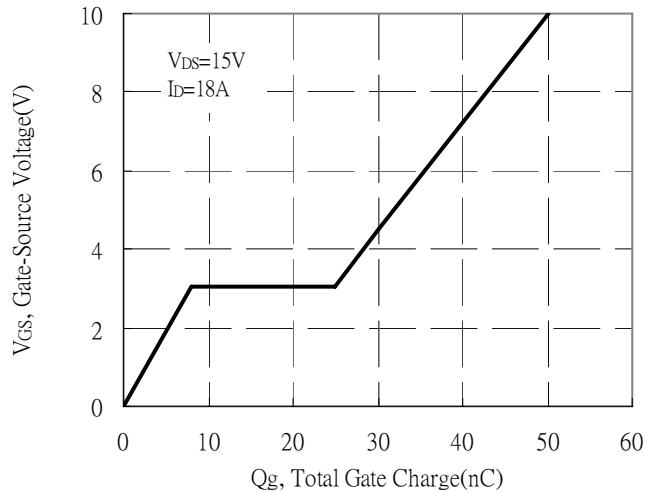
Threshold Voltage vs Junction Temperature



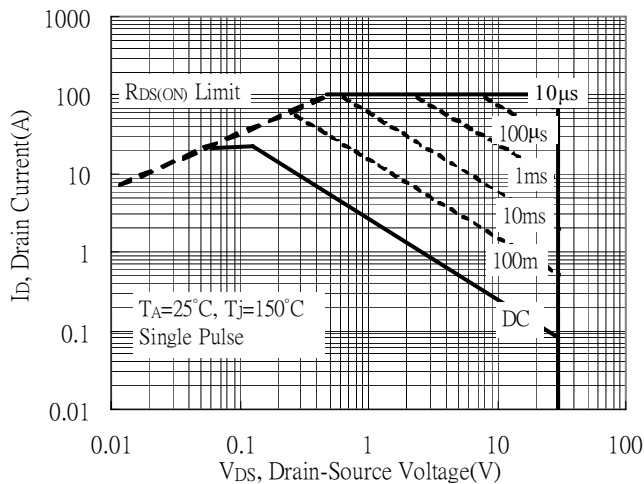
Forward Transfer Admittance vs Drain Current



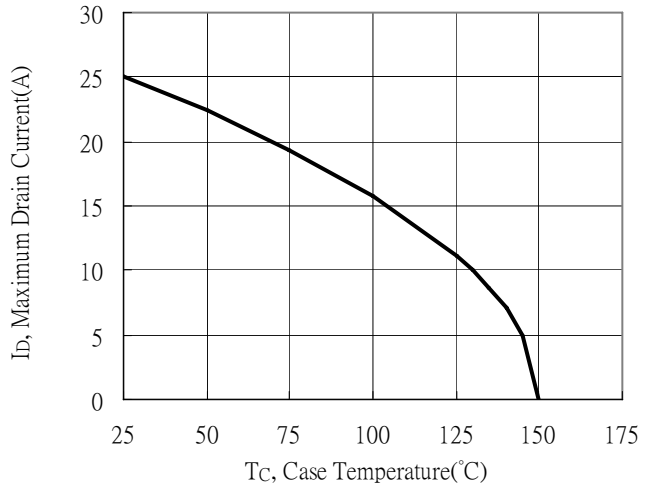
Gate Charge Characteristics



Maximum Safe Operating Area

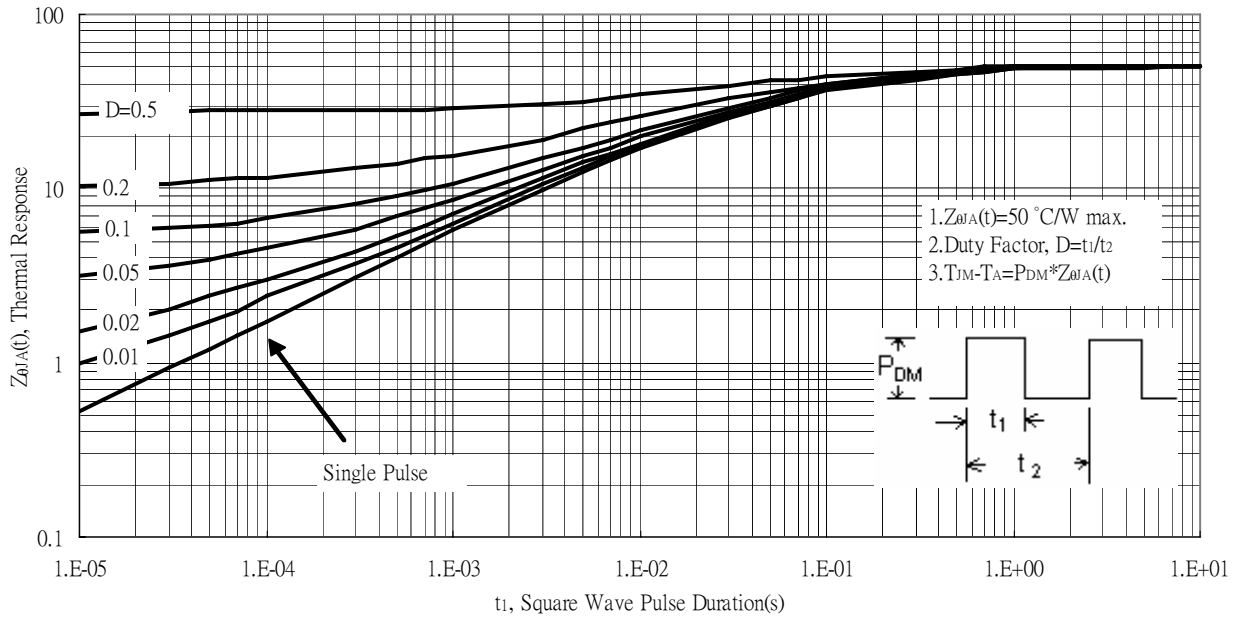


Maximum Drain Current vs Case Temperature

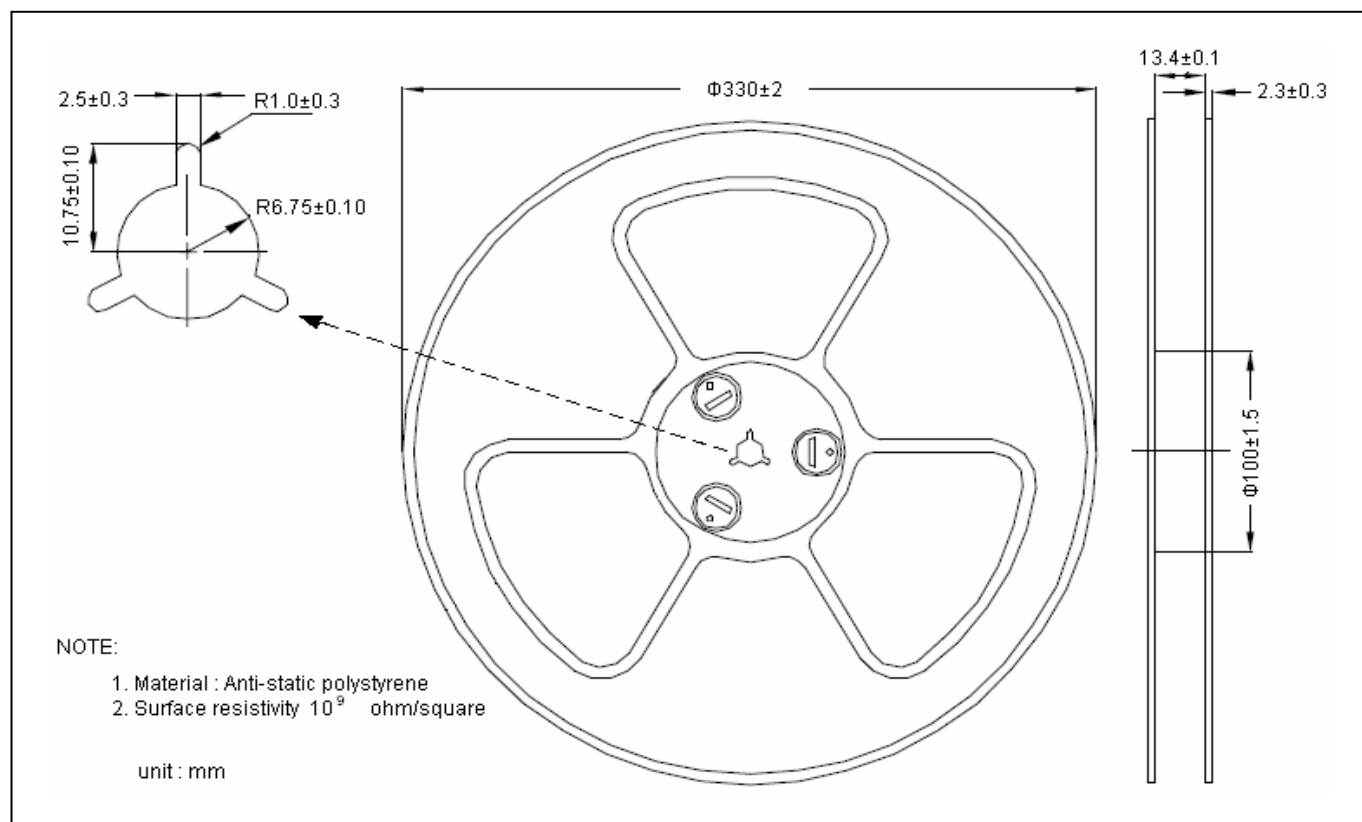


Typical Characteristics(Cont.)

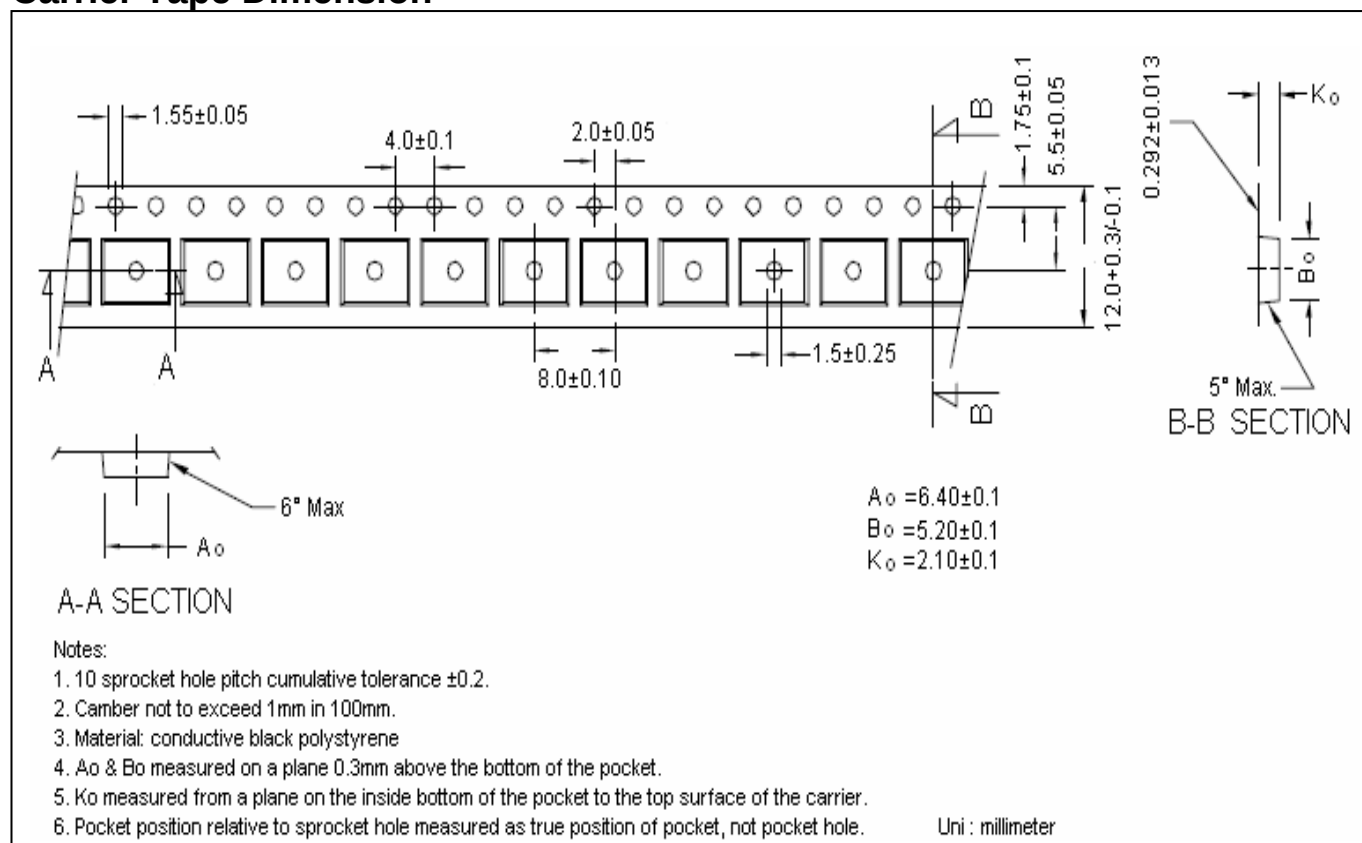
Transient Thermal Response Curves



Reel Dimension



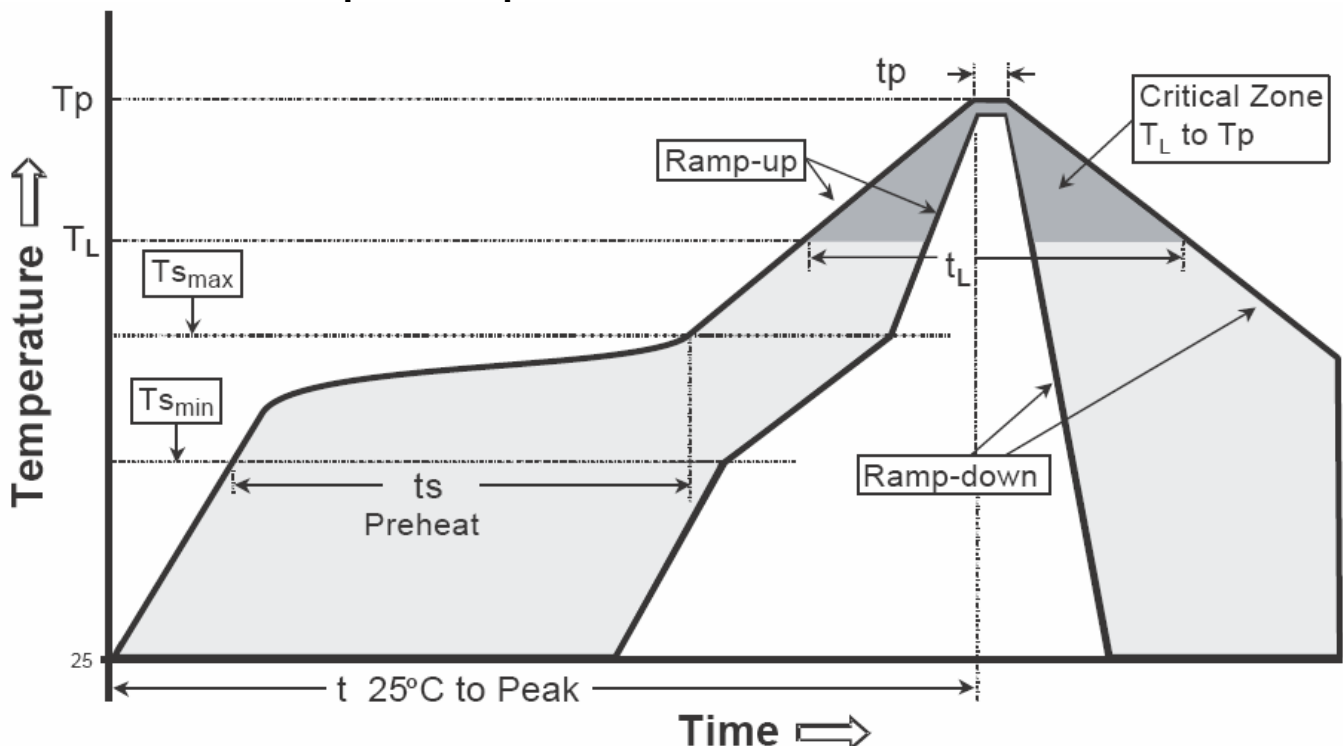
Carrier Tape Dimension



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

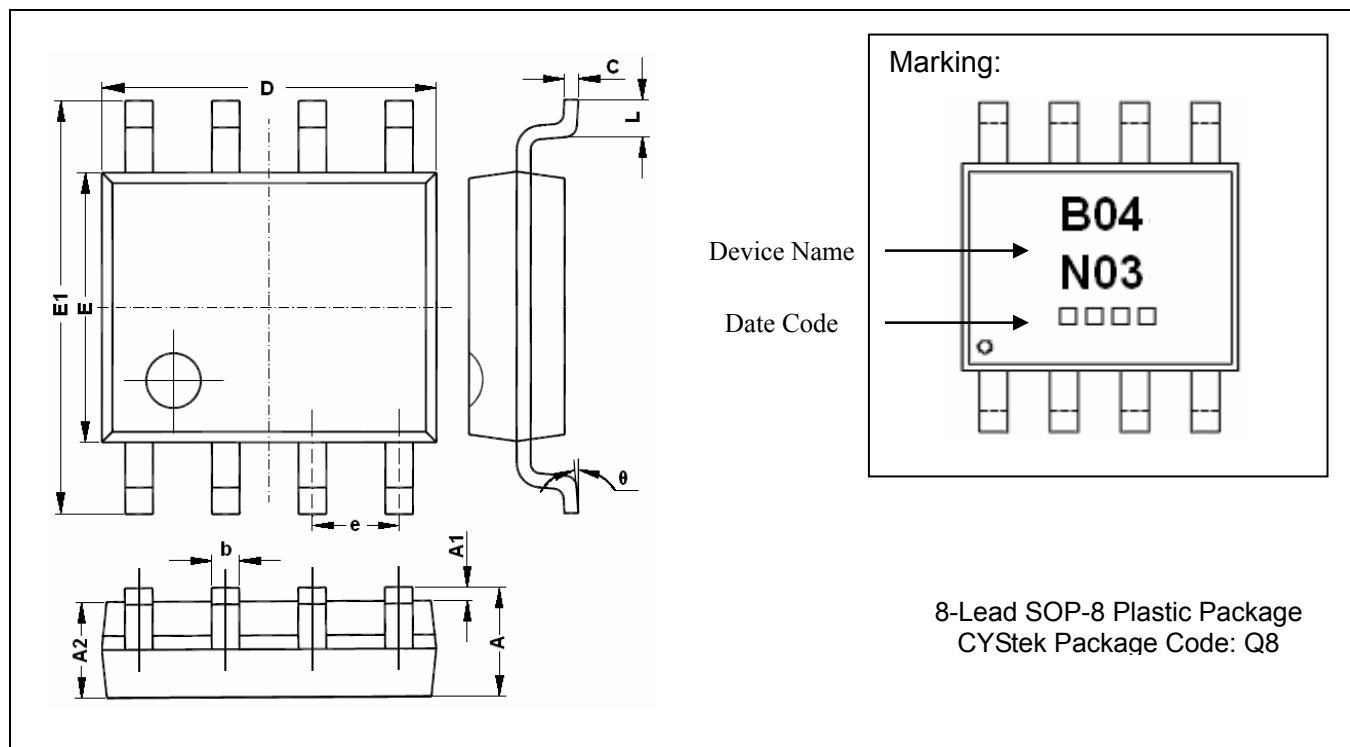
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts min)	100°C	150°C
-Temperature Max(Ts max)	150°C	200°C
-Time(ts min to ts max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (Tl)	183°C	217°C
- Time (tL)	60-150 seconds	60-150 seconds
Peak Temperature(Tp)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOP-8 Dimension



DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069	E	3.800	4.000	0.150	0.157
A1	0.100	0.250	0.004	0.010	E1	5.800	6.200	0.228	0.244
A2	1.350	1.550	0.053	0.061	e	1.270	(BSC)	0.050	(BSC)
b	0.330	0.510	0.013	0.020	L	0.400	1.270	0.016	0.050
c	0.170	0.250	0.006	0.010	θ	0	8°	0	8°
D	4.700	5.100	0.185	0.200					

Notes: 1. Controlling dimension: millimeters.

2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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